

128M-Bit (8Mx16) CMOS MASK ROM

FEATURES

- 8,388,608 x 16 bit organization
- Fast access time
Random Access Time/Page Access Time
3.3V Operation : 100/30ns(Max.)@ $C_L=50pF$,
120/40ns(Max.)@ $C_L=100pF$
3.0V Operation : 120/40ns(Max.)@ $C_L=100pF$
8 Words / 16 Bytes page access
- Supply voltage : single +3.0V/ single +3.3V
- Current consumption
Operating : 80mA(Max.)
Standby : 30 μ A(Max.)
- Fully static operation
- All inputs and outputs TTL compatible
- Three state outputs
- Package
K3P9V(U)4000A-GC : 44-SOP-600

GENERAL DESCRIPTION

The K3P9V(U)4000A-GC is a fully static mask programmable ROM organized as 8,388,608 x 16 bit. It is fabricated using silicon gate CMOS process technology.

This device includes page read mode function, page read mode allows 8 words of data to read fast in the same page, \overline{CE} and $A_3 \sim A_{22}$ should not be changed.

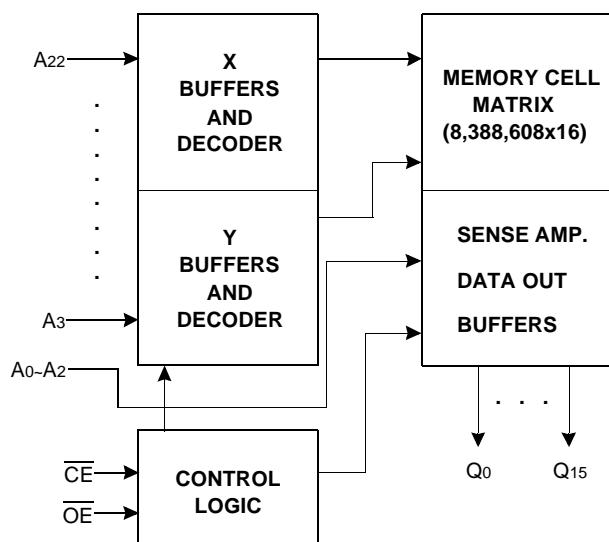
This device operates with 3.0V or 3.3V power supply, and all inputs and outputs are TTL compatible.

Because of its asynchronous operation, it requires no external clock assuring extremely easy operation.

It is suitable for use in program memory of microprocessor, and data memory, character generator.

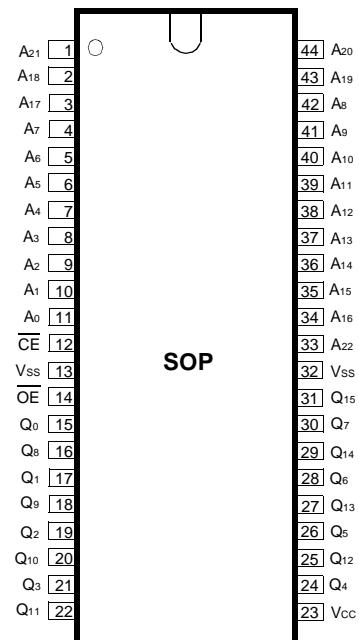
The K3P9V(U)4000A-GC is packaged in a 44-SOP.

FUNCTIONAL BLOCK DIAGRAM



| Pin Name | Pin Function |
|-----------------|---------------------|
| A0 - A2 | Page Address Inputs |
| A3 - A22 | Address Inputs |
| Q0 - Q15 | Data Outputs |
| \overline{CE} | Chip Enable |
| \overline{OE} | Output Enable |
| Vcc | Power |
| Vss | Ground |

PIN CONFIGURATION



K3P9V(U)4000A-GC



ELECTRONICS

ABSOLUTE MAXIMUM RATINGS

| Item | Symbol | Rating | Unit |
|------------------------------------|--------|--------------|------|
| Voltage on Any Pin Relative to Vss | VIN | -0.3 to +4.5 | V |
| Temperature Under Bias | TBIAS | -10 to +85 | °C |
| Storage Temperature | TSTG | -55 to +150 | °C |

NOTE : Permanent device damage may occur if "ABSOLUTE MAXIMUM RATINGS" are exceeded. Functional operation should be restricted to the conditions as detailed in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS(Voltage reference to Vss, TA=0 to 70°C)

| Item | Symbol | Min | Typ | Max | Unit |
|----------------|--------|---------|---------|---------|------|
| Supply Voltage | Vcc | 2.7/3.0 | 3.0/3.3 | 3.3/3.6 | V |
| Supply Voltage | Vss | 0 | 0 | 0 | V |

DC CHARACTERISTICS

| Parameter | Symbol | Test Conditions | Min | Max | Unit |
|--------------------------------|--------|---|---------------------|-------------|-------|
| Operating Current | Icc | Cycle=5MHz, all outputs open, $\overline{CE}=\overline{OE}=VIL$, $VIN=0.45V$ to $2.4V$ (AC Test Condition) | $Vcc=3.3V \pm 0.3V$ | - | 80 mA |
| Standby Current(TTL) | IsB1 | $\overline{CE}=Vih$, all outputs open | - | 500 μA | |
| Standby Current(CMOS) | IsB2 | $\overline{CE}=Vcc$, all outputs open | - | 30 μA | |
| Input Leakage Current | ILI | $VIN=0$ to Vcc | - | 10 μA | |
| Output Leakage Current | ILO | $VOUT=0$ to Vcc | - | 10 μA | |
| Input High Voltage, All Inputs | VIH | | 2.0 | $Vcc+0.3$ | V |
| Input Low Voltage, All Inputs | VIL | | -0.3 | 0.6 | V |
| Output High Voltage Level | VOH | $Ioh=-400\mu A$ | 2.4 | - | V |
| Output Low Voltage Level | VOL | $Iol=2.1mA$ | - | 0.4 | V |

NOTE : Minimum DC Voltage(VIL) is -0.3V an input pins. During transitions, this level may undershoot to -2.0V for periods <20ns.

Maximum DC voltage on input pins(VIH) is $Vcc+0.3V$ which, during transitions, may overshoot to $Vcc+2.0V$ for periods <20ns.

MODE SELECTION

| CE | OE | Mode | Data | Power |
|----|----|-----------|--------|---------|
| H | X | Standby | High-Z | Standby |
| L | H | Operating | High-Z | Active |
| L | L | Operating | Dout | Active |

CAPACITANCE(TA=25°C, f=1.0MHz)

| Item | Symbol | Test Conditions | Min | Max | Unit |
|--------------------|--------|-----------------|-----|-----|------|
| Output Capacitance | Cout | $Vout=0V$ | - | 12 | pF |
| Input Capacitance | Cin | $Vin=0V$ | - | 12 | pF |

NOTE : Capacitance is periodically sampled and not 100% tested.



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AC CHARACTERISTICS($T_A=0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$, $V_{CC}=3.3\text{V}/3.0\text{V}\pm 0.3\text{V}$, unless otherwise noted.)**TEST CONDITIONS**

| Item | Value |
|--------------------------------|--|
| Input Pulse Levels | 0.45V to 2.4V |
| Input Rise and Fall Times | 10ns |
| Input and Output timing Levels | 1.5V |
| Output Loads | 1 TTL Gate and $C_L=50\text{pF}$ or 100pF |

READ CYCLE

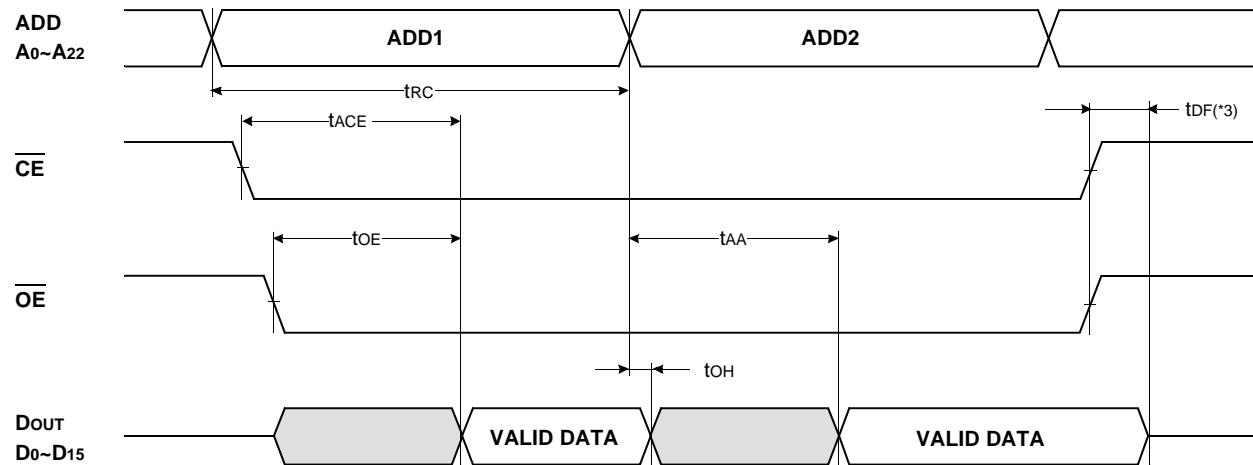
| Item | Symbol | K3P9V4000A-GC10 ($C_L=50\text{pF}$) | | K3P9V4000A-GC12 ($C_L=100\text{pF}$) | | K3P9U4000A-GC12 ($C_L=100\text{pF}$) | | Unit |
|---|------------------|--|-----|---|-----|---|-----|------|
| | | Min | Max | Min | Max | Min | Max | |
| Read Cycle Time | t _{RC} | 100 | | 120 | | 120 | | ns |
| Chip Enable Access Time | t _{ACE} | | 100 | | 120 | | 120 | ns |
| Address Access Time | t _{AA} | | 100 | | 120 | | 120 | ns |
| Page Address Access Time | t _{PA} | | 30 | | 40 | | 40 | ns |
| Output Enable Access Time | t _{OE} | | 30 | | 40 | | 40 | ns |
| Output or Chip Disable to Output High-Z | t _{DF} | | 20 | | 20 | | 20 | ns |
| Output Hold from Address Change | t _{OH} | 0 | | 0 | | 0 | | ns |

NOTE : Page Address is determined as A₀, A₁, A₂

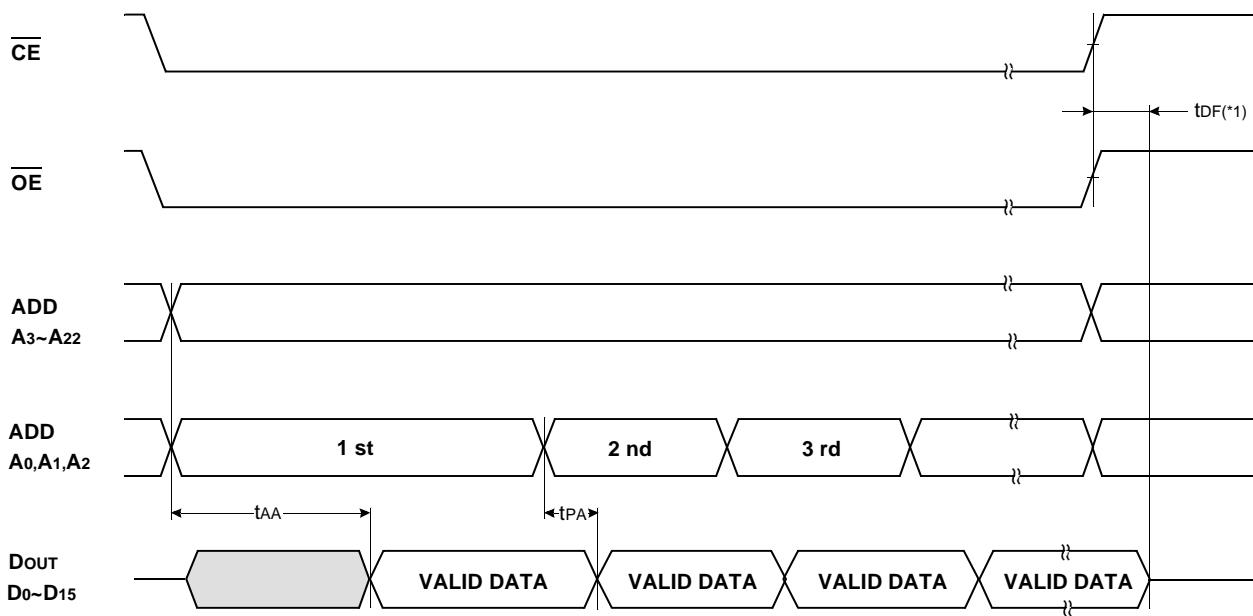
ELECTRONICS

TIMING DIAGRAM

READ



PAGE READ



NOTES :

*1. t_{DF} is defined as the time at which the outputs achieve the open circuit condition and is not referenced to V_{OH} or V_{OL} level.